

ON Semiconductor

Is Now

onsemi™

To learn more about onsemi™, please visit our website at
www.onsemi.com

onsemi and **onsemi** and other names, marks, and brands are registered and/or common law trademarks of Semiconductor Components Industries, LLC dba "**onsemi**" or its affiliates and/or subsidiaries in the United States and/or other countries. **onsemi** owns the rights to a number of patents, trademarks, copyrights, trade secrets, and other intellectual property. A listing of **onsemi** product/patent coverage may be accessed at www.onsemi.com/site/pdf/Patent-Marking.pdf. **onsemi** reserves the right to make changes at any time to any products or information herein, without notice. The information herein is provided "as-is" and **onsemi** makes no warranty, representation or guarantee regarding the accuracy of the information, product features, availability, functionality, or suitability of its products for any particular purpose, nor does **onsemi** assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages. Buyer is responsible for its products and applications using **onsemi** products, including compliance with all laws, regulations and safety requirements or standards, regardless of any support or applications information provided by **onsemi**. "Typical" parameters which may be provided in **onsemi** data sheets and/or specifications can and do vary in different applications and actual performance may vary over time. All operating parameters, including "Typicals" must be validated for each customer application by customer's technical experts. **onsemi** does not convey any license under any of its intellectual property rights nor the rights of others. **onsemi** products are not designed, intended, or authorized for use as a critical component in life support systems or any FDA Class 3 medical devices or medical devices with a same or similar classification in a foreign jurisdiction or any devices intended for implantation in the human body. Should Buyer purchase or use **onsemi** products for any such unintended or unauthorized application, Buyer shall indemnify and hold **onsemi** and its officers, employees, subsidiaries, affiliates, and distributors harmless against all claims, costs, damages, and expenses, and reasonable attorney fees arising out of, directly or indirectly, any claim of personal injury or death associated with such unintended or unauthorized use, even if such claim alleges that **onsemi** was negligent regarding the design or manufacture of the part. **onsemi** is an Equal Opportunity/Affirmative Action Employer. This literature is subject to all applicable copyright laws and is not for resale in any manner. Other names and brands may be claimed as the property of others.

NVATS5A302PLZ

Power MOSFET

–60 V, 13 mΩ, –80 A, P-Channel



ON Semiconductor®

www.onsemi.com

Automotive Power MOSFET designed for compact and efficient designs and including high thermal performance.

AEC-Q101 qualified MOSFET and PPAP capable suitable for automotive applications.

Features

- Low On-Resistance
- High Current Capability
- 100% Avalanche Tested
- AEC-Q101 qualified and PPAP capable
- ATPAK package is pin-compatible with DPAK (TO-252)
- Pb-Free, Halogen Free and RoHS compliance

Typical Applications

- Reverse Battery Protection
- Load Switch
- Automotive Front Lighting
- Automotive Body Controllers

SPECIFICATIONS

ABSOLUTE MAXIMUM RATING at Ta = 25°C (Note 1)

Parameter	Symbol	Value	Unit
Drain to Source Voltage	V _{DSS}	–60	V
Gate to Source Voltage	V _{GSS}	±20	V
Drain Current (DC)	I _D	–80	A
Drain Current (Pulse) PW ≤ 10 μs, duty cycle ≤ 1%	I _{DP}	–320	A
Power Dissipation T _c = 25°C	P _D	84	W
Operating Junction and Storage Temperature	T _j , T _{stg}	–55 to +175	°C
Avalanche Energy (Single Pulse) (Note 2)	E _{AS}	197	mJ
Avalanche Current (Note 3)	I _{AV}	–42	A

Note 1 : Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

2 : V_{DD} = –36 V, L = 100 μH, I_{AV} = –42 A (Fig.1)

3 : L ≤ 100 μH, Single pulse

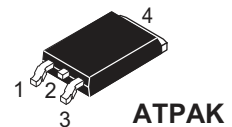
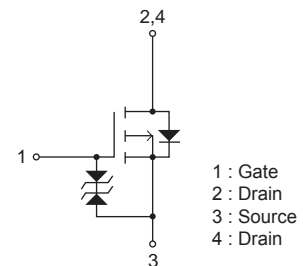
THERMAL RESISTANCE RATINGS

Parameter	Symbol	Value	Unit
Junction to Case Steady State (T _c = 25°C)	R _{θJC}	1.78	°C/W
Junction to Ambient (Note 4)	R _{θJA}	79.1	°C/W

Note 4 : Surface mounted on FR4 board using a 130 mm², 1 oz. Cu pad.

V _{DSS}	R _{DS(on)} Max	I _D Max
–60 V	13 mΩ @ –10 V	–80 A
	18 mΩ @ –4.5 V	

ELECTRICAL CONNECTION P-Channel



MARKING



ORDERING INFORMATION

See detailed ordering and shipping information on page 6 of this data sheet.

NVATS5A302PLZ

ELECTRICAL CHARACTERISTICS at Ta = 25°C (Note 5)

Parameter	Symbol	Conditions	Value			Unit
			min	typ	max	
Drain to Source Breakdown Voltage	V(BR)DSS	$I_D = -1 \text{ mA}, V_{GS} = 0 \text{ V}$	-60			V
Zero-Gate Voltage Drain Current	I_{DSS}	$V_{DS} = -60 \text{ V}, V_{GS} = 0 \text{ V}$			-10	μA
Gate to Source Leakage Current	I_{GSS}	$V_{GS} = \pm 16 \text{ V}, V_{DS} = 0 \text{ V}$			± 10	μA
Gate Threshold Voltage	$V_{GS(th)}$	$V_{DS} = -10 \text{ V}, I_D = -1 \text{ mA}$	-1.2		-2.6	V
Forward Transconductance	g_{FS}	$V_{DS} = -10 \text{ V}, I_D = -35 \text{ A}$		75		S
Static Drain to Source On-State Resistance	$R_{DS(on)1}$	$I_D = -35 \text{ A}, V_{GS} = -10 \text{ V}$		10	13	$\text{m}\Omega$
	$R_{DS(on)2}$	$I_D = -35 \text{ A}, V_{GS} = -4.5 \text{ V}$		13	18	$\text{m}\Omega$
Input Capacitance	C_{iss}	$V_{DS} = -20 \text{ V}, f = 1 \text{ MHz}$		5,400		pF
Output Capacitance	C_{oss}			500		pF
Reverse Transfer Capacitance	C_{rss}			370		pF
Turn-ON Delay Time	$t_{d(on)}$		See Fig.2		35	
Rise Time	t_r			430		ns
Turn-OFF Delay Time	$t_{d(off)}$			420		ns
Fall Time	t_f			500		ns
Total Gate Charge	Q_g	$V_{DS} = -36 \text{ V}, V_{GS} = -10 \text{ V}, I_D = -70 \text{ A}$		115		nC
Gate to Source Charge	Q_{gs}			20		nC
Gate to Drain "Miller" Charge	Q_{gd}			25		nC
Forward Diode Voltage	V_{SD}		$I_S = -70 \text{ A}, V_{GS} = 0 \text{ V}$		-1.0	-1.5

Note 5 : Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

Fig.1 Unclamped Inductive Switching Test Circuit

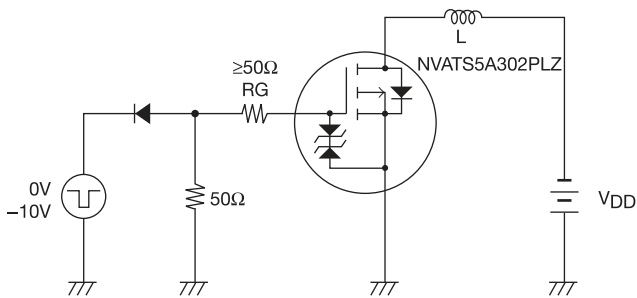
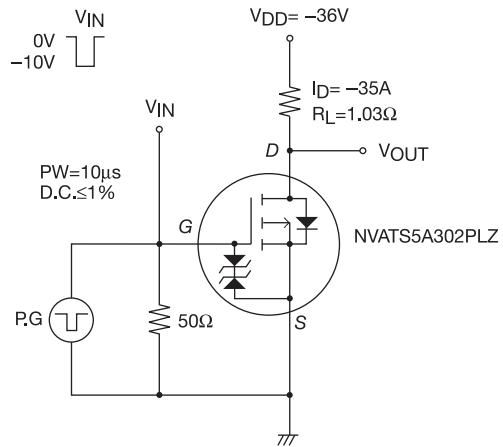
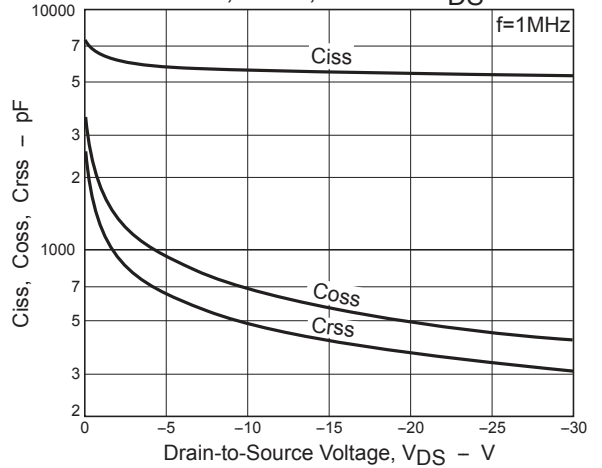
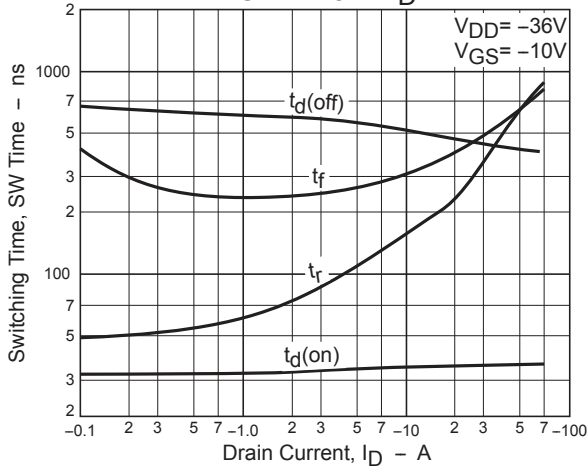
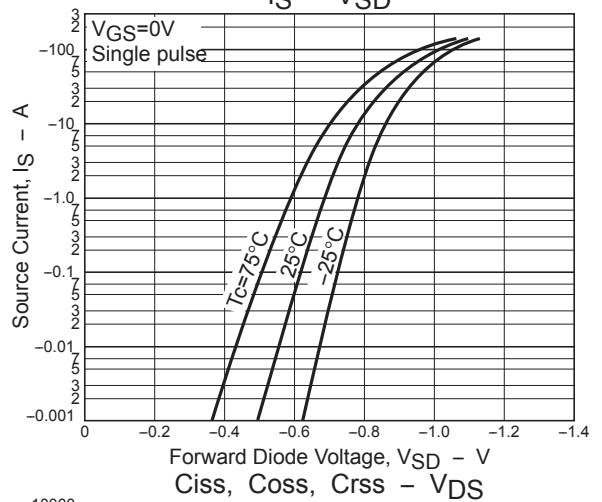
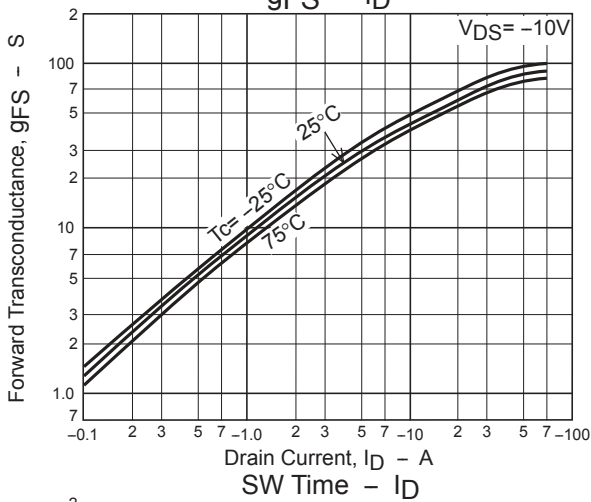
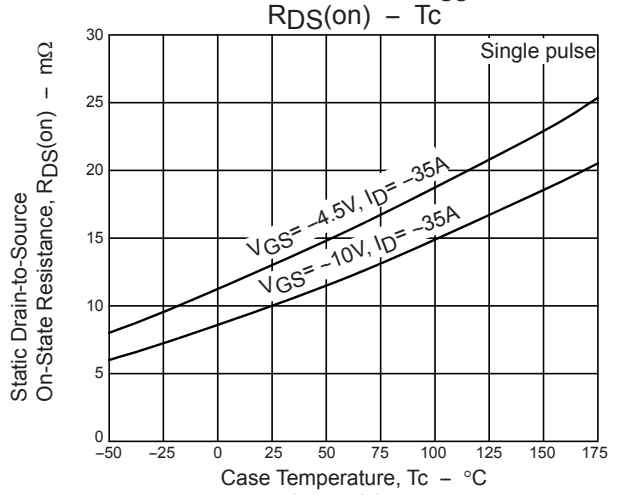
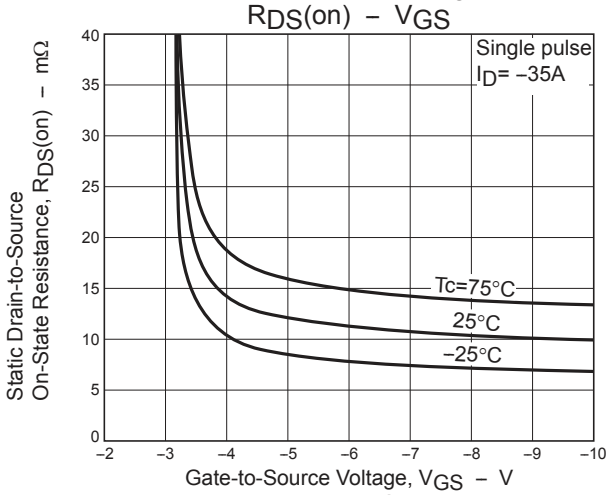
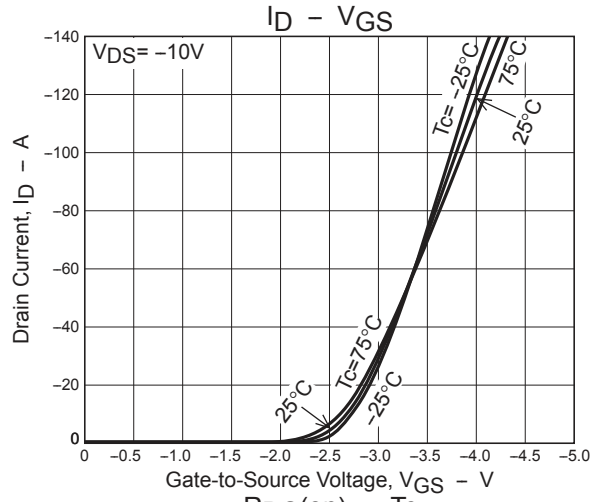
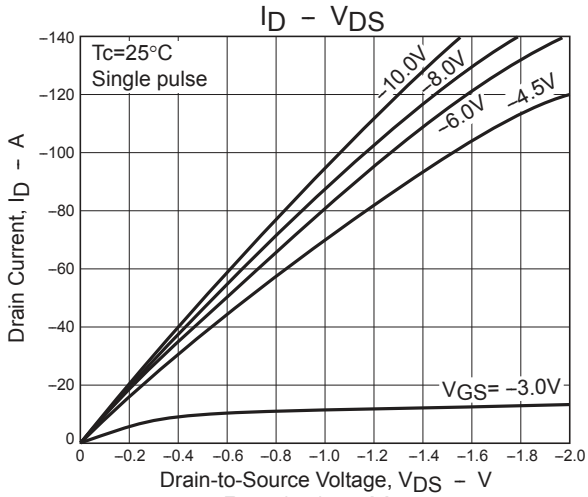


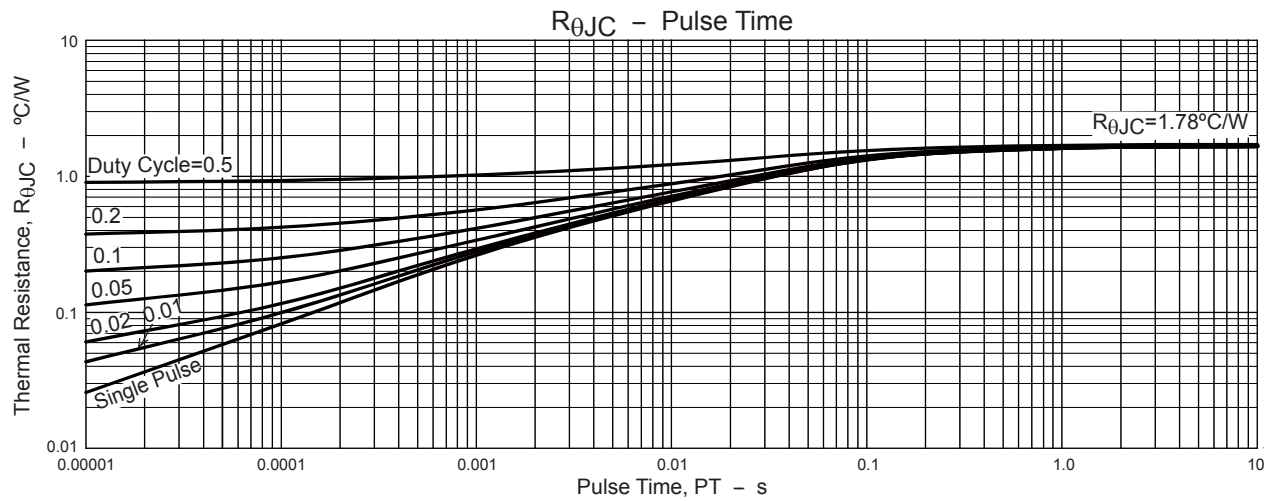
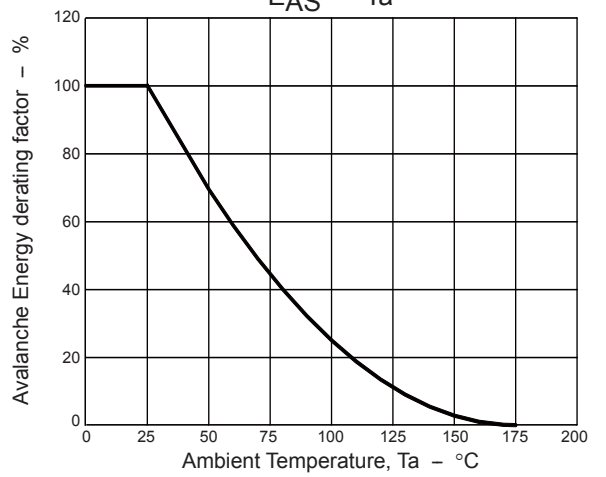
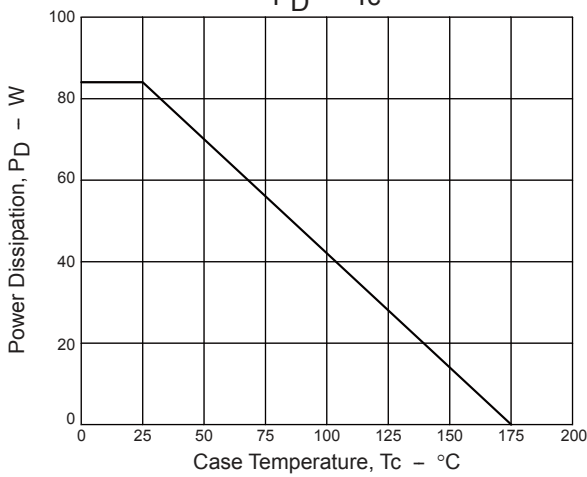
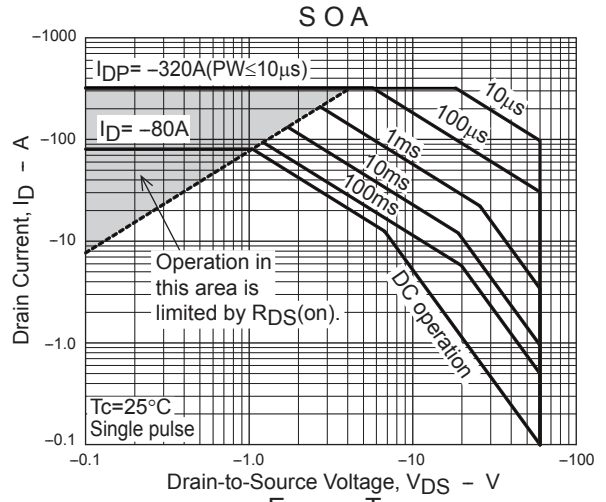
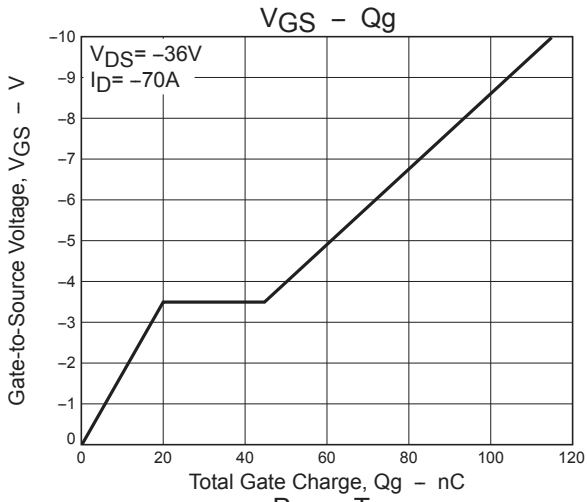
Fig.2 Switching Time Test Circuit



NVATS5A302PLZ



NVATS5A302PLZ



NVATS5A302PLZ

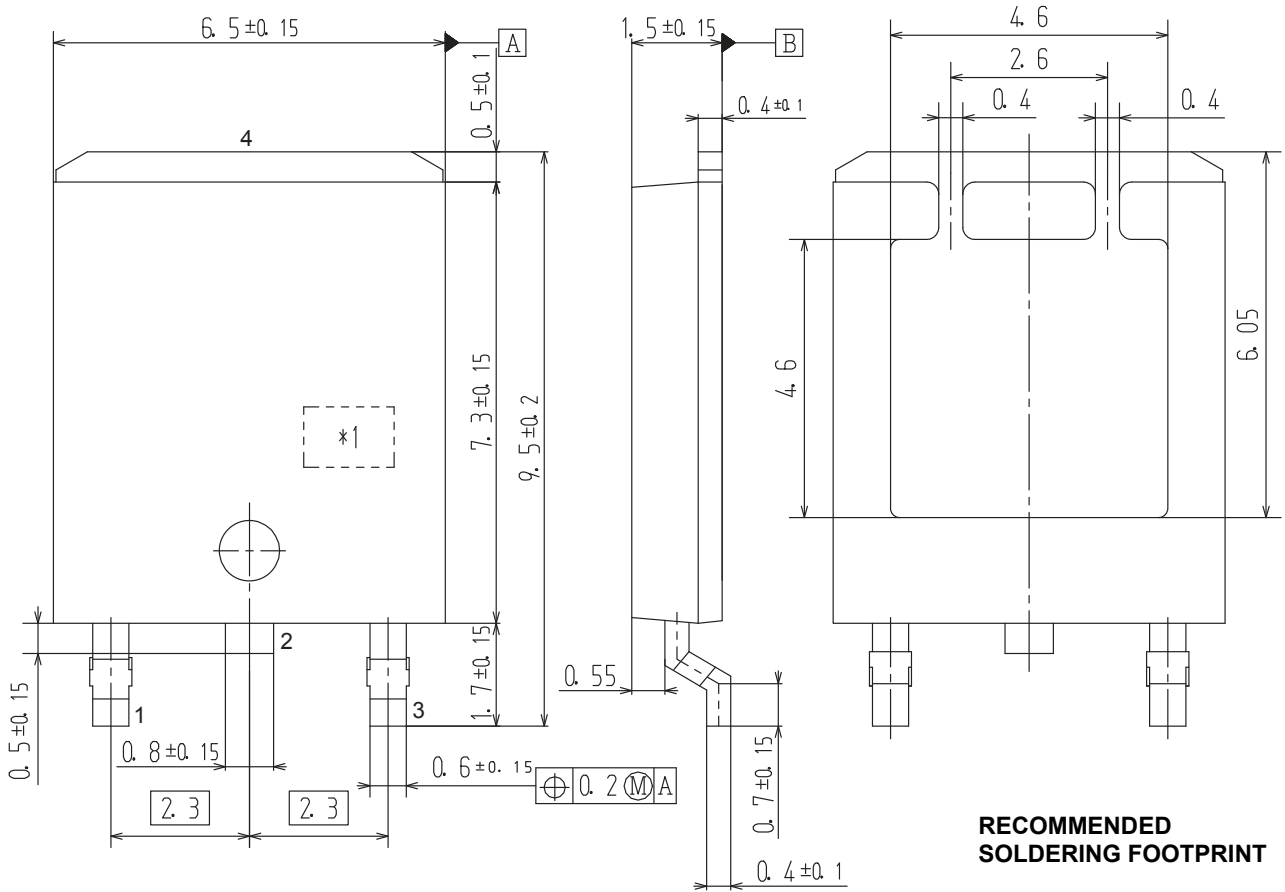
PACKAGE DIMENSIONS

unit : mm

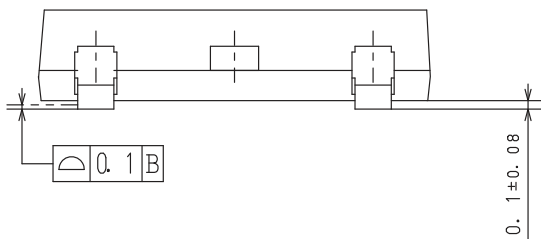
DPAK (Single Gauge) / ATPAK

CASE 369AM

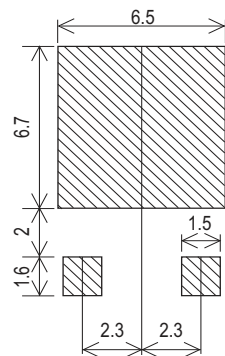
ISSUE O



RECOMMENDED SOLDERING FOOTPRINT



- 1 : Gate
- 2 : Drain
- 3 : Source
- 4 : Drain



Pin2 is idle pin with electrical designation only carried

*1: Lot indication

NVATS5A302PLZ

ORDERING INFORMATION

Device	Marking	Package	Shipping (Qty / Packing)
NVATS5A302PLZT4G	ATP302	DPAK(Single Gauge) / ATPAK (Pb-Free / Halogen Free)	3,000 / Tape & Reel

† For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D. http://www.onsemi.com/pub_link/Collateral/BRD8011-D.PDF

Note on usage : Since the NVATS5A302PLZ is a MOSFET product, please avoid using this device in the vicinity of highly charged objects.

ON Semiconductor and the ON Semiconductor logo are trademarks of Semiconductor Components Industries, LLC dba ON Semiconductor or its subsidiaries in the United States and/or other countries. ON Semiconductor owns the rights to a number of patents, trademarks, copyrights, trade secrets, and other intellectual property. A listing of ON Semiconductor's product/patent coverage may be accessed at www.onsemi.com/site/pdf/Patent-Marking.pdf. ON Semiconductor reserves the right to make changes without further notice to any products herein. ON Semiconductor makes no warranty, representation or guarantee regarding the suitability of its products for any particular purpose, nor does ON Semiconductor assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages. Buyer is responsible for its products and applications using ON Semiconductor products, including compliance with all laws, regulations and safety requirements or standards, regardless of any support or applications information provided by ON Semiconductor. "Typical" parameters which may be provided in ON Semiconductor data sheets and/or specifications can and do vary in different applications and actual performance may vary over time. All operating parameters, including "Typicals" must be validated for each customer application by customer's technical experts. ON Semiconductor does not convey any license under its patent rights nor the rights of others. ON Semiconductor products are not designed, intended, or authorized for use as a critical component in life support systems or any FDA Class 3 medical devices or medical devices with a same or similar classification in a foreign jurisdiction or any devices intended for implantation in the human body. Should Buyer purchase or use ON Semiconductor products for any such unintended or unauthorized application, Buyer shall indemnify and hold ON Semiconductor and its officers, employees, subsidiaries, affiliates, and distributors harmless against all claims, costs, damages, and expenses, and reasonable attorney fees arising out of, directly or indirectly, any claim of personal injury or death associated with such unintended or unauthorized use, even if such claim alleges that ON Semiconductor was negligent regarding the design or manufacture of the part. ON Semiconductor is an Equal Opportunity/Affirmative Action Employer. This literature is subject to all applicable copyright laws and is not for resale in any manner.